





IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the application of:

SHI-QING WANG, ET AL

Docket: 30-4687 (4780)

Serial Number: 09/328,646

Group Art Unit: 2811

Filed: June 9, 1999

Examiner: H. Vu

For: INTEGRATED CIRCUITS WITH MULTIPLE LOW DIELECTRIC-

CONSTANT INTER-METAL DIELECTRICS

FAX COVER SHEET

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FROM:

Richard S. Roberts

Reg. No. 27941 P.O. Box 484

Princeton, New Jersey 08542

(609) 921-3500

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AMENDMENT

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Sir:

In response to the Office Action mailed August 14, 2002, please amend the above identified patent application as follows:

In the claims:

CLEAN COPY OF THE AMENDED CLAIMS

EI Dt

23. (Amended) An integrated circuit structure which comprises a substrate and (a) an organic layer on a surface of the substrate which comprises a pattern of metal lines on the substrate and an organic dielectric on the substrate surface between the metal lines, and wherein the organic dielectric comprises a dielectric selected from the group consisting of alkoxysilane polymers, organic siloxanes,